



UNIVERSITY AT ALBANY
State University of New York

Lithographic characterization of low-order aberrations in the Berkeley MET tool

Patrick Naulleau

CNSE, University at Albany, State University of New York

Jason P. Cain

EECS, University of California, Berkeley

Kim Dean

SEMATECH

Kenneth A. Goldberg

CXRO, Lawrence Berkeley National Laboratory

Supported by SEMATECH

Patrick Naulleau





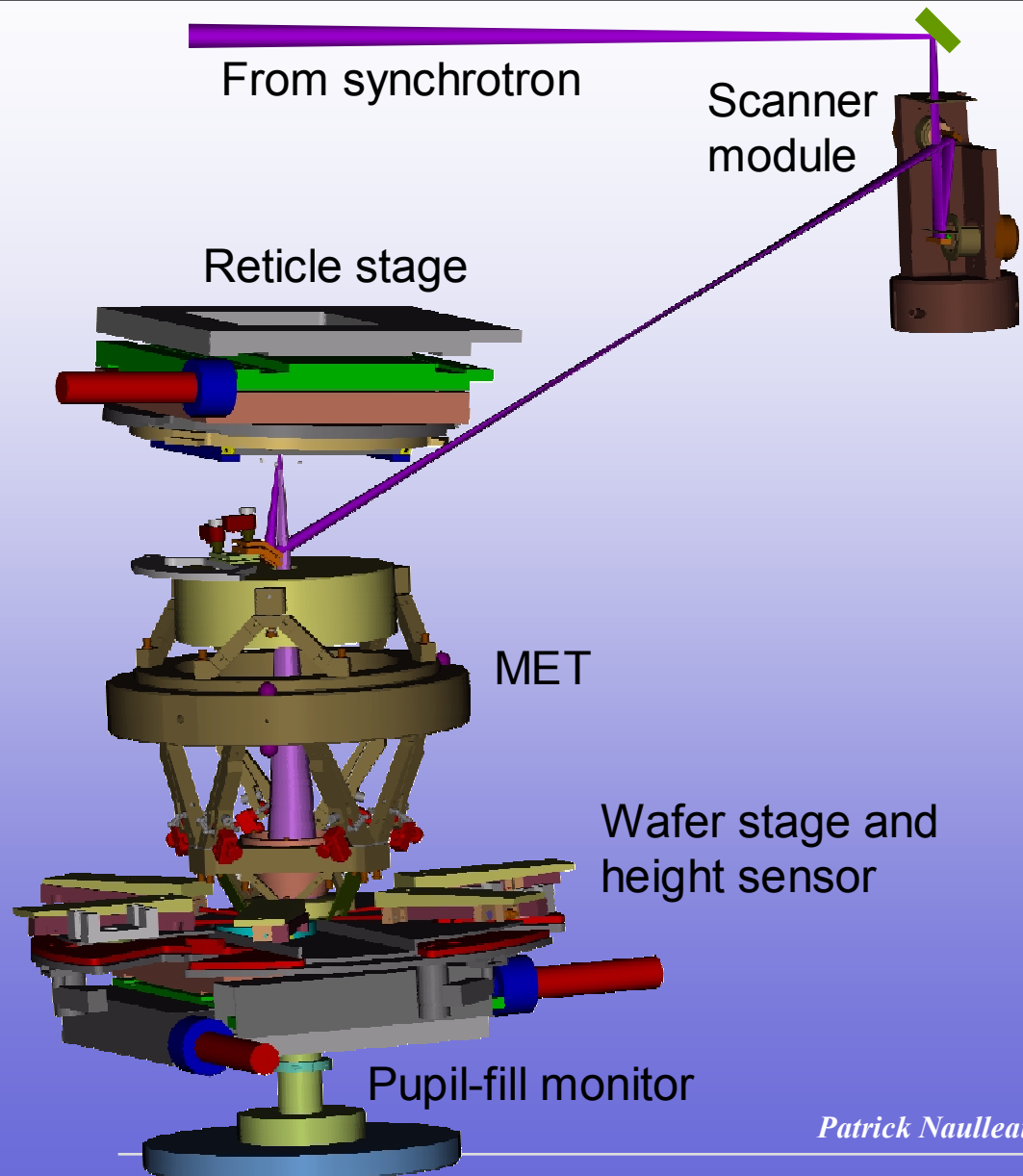
Outline

- System description
- Experimental performance limit
- Lithographic measurement of cross-field astigmatism
- Lithographic measurement of spherical error
- Qualitative characterization of coma
- Predicted impact of aberrations on performance



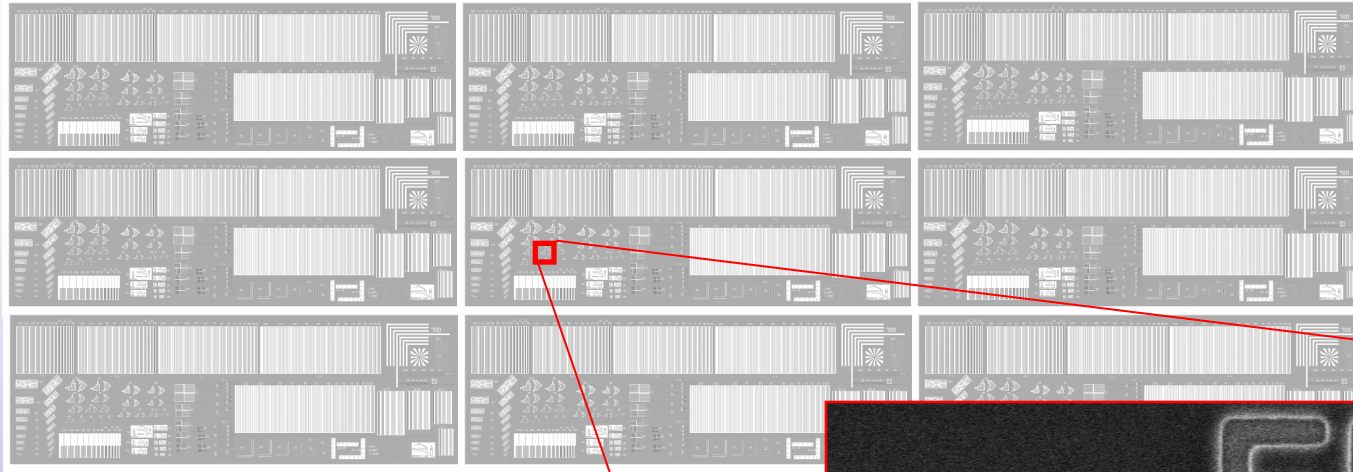
Berkeley MET exposure tool

- Based on MET optic
- Magnification = 5x, NA = 0.3
- Rayleigh resolution = 27 nm
- Field size = 200x600 μm
- Programmable coherence illuminator for low k_1
- Reticle and wafer load-lock and manual transfer systems
- Wafer-height sensor
- nm-resolution wafer-height sensor and focus actuation
- Pupil-fill monitor

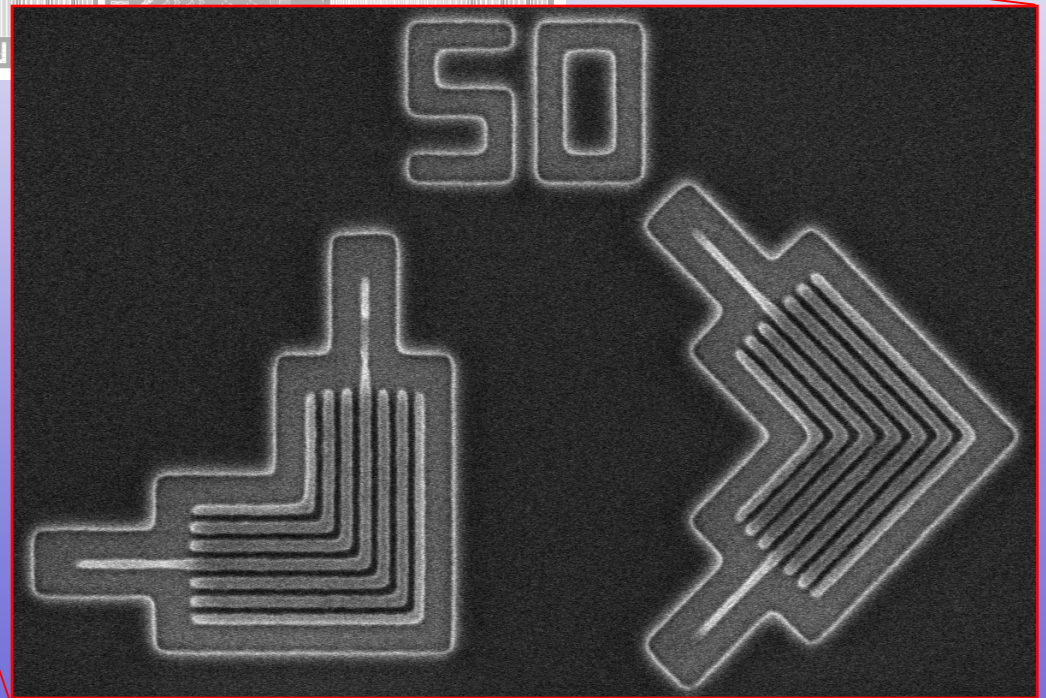




50-nm elbow pattern used to characterize astigmatism across field

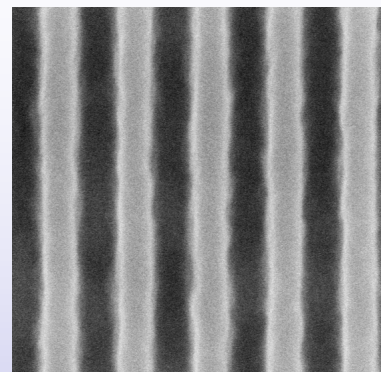
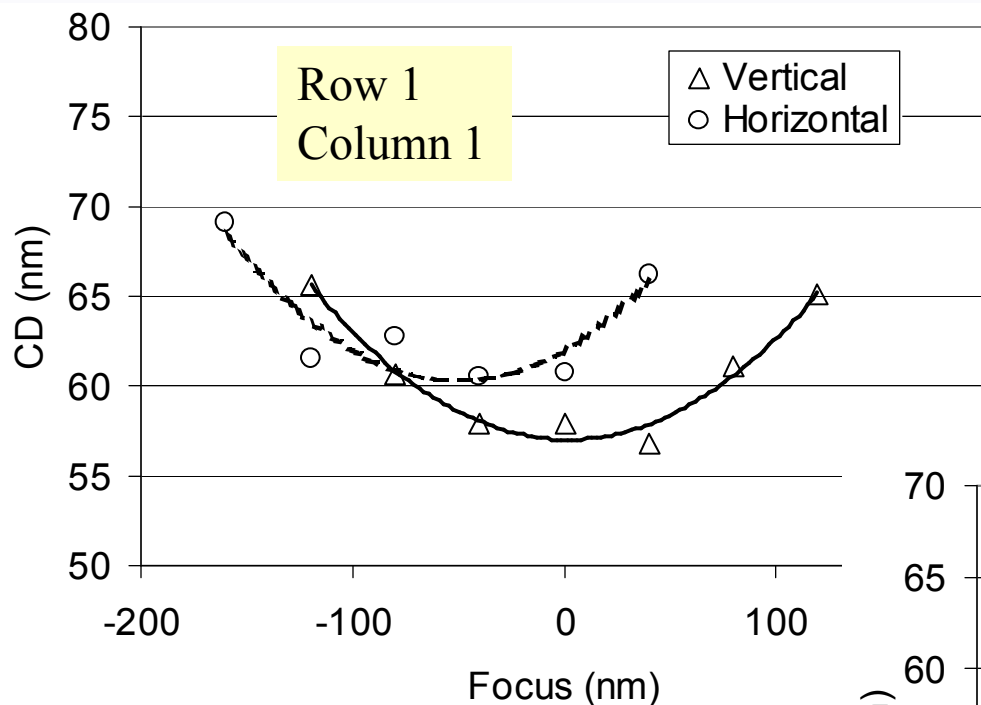


- Elbow feature block provides 4 independent orientations within small area (focus and dose constant over the feature set)
- Orientation dependence of focus used to quantify astigmatism

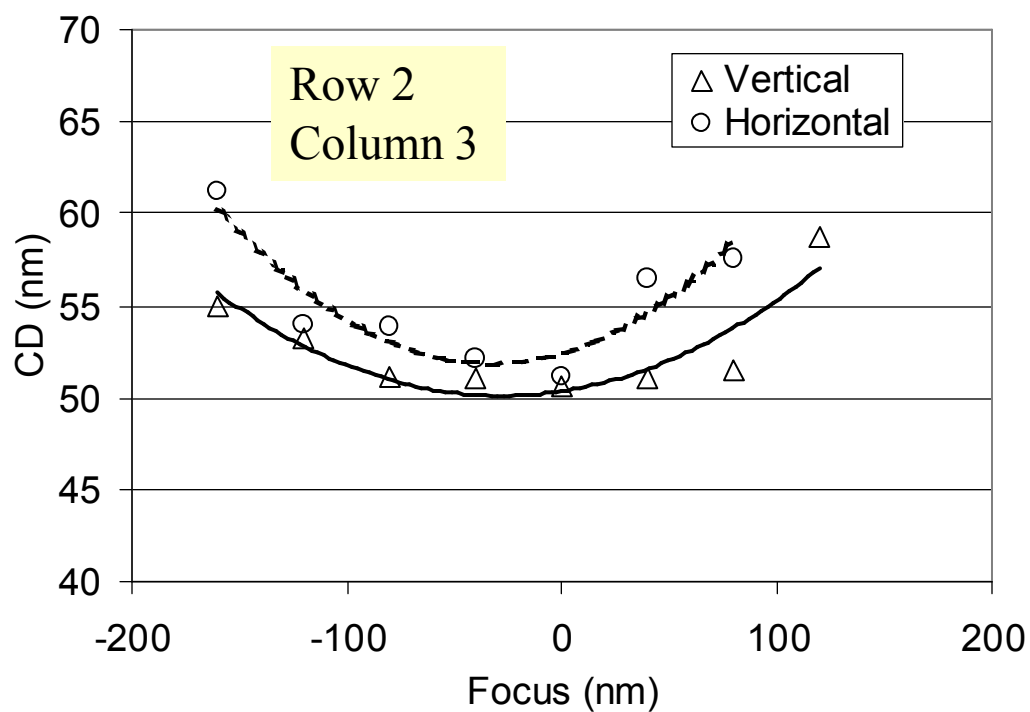




Orientation dependence of 50-nm performance



Representative
image used to
determine focus
vs orientation



- Significant astigmatism changes evident
- HV bias observed
 - Matches orientation expected from mask shadowing



Cross-field astigmatism

Lithographic measurement

0° astigmatism

-0.467	-0.434	-0.188
-0.518	-0.427	-0.036
-0.481	-0.511	-0.002

45° astigmatism

-0.003	-0.237	-0.314
-0.032	-0.079	-0.216
-0.032	-0.089	-0.160

Total astigmatism magnitude

0.468	0.494	0.365
0.519	0.433	0.219
0.482	0.518	0.160

Field-averaged astigmatism = 0.41 nm rms
Measurement reproducibility better than 0.1 nm

Patrick Naulleau



Cross-field astigmatism

Lithographic measurement

0° astigmatism

-0.467	-0.434	-0.188
-0.518	-0.427	-0.036
-0.481	-0.511	-0.002

45° astigmatism

-0.003	-0.237	-0.314
-0.032	-0.079	-0.216
-0.032	-0.089	-0.160

Total astigmatism magnitude

0.468	0.494	0.365
0.519	0.433	0.219
0.482	0.518	0.160

Interferometric measurement (10/03)

0° astigmatism

-0.239	0.001	0.317
-0.355	-0.073	0.379
-0.275	-0.065	0.688

45° astigmatism

0.157	-0.035	-0.356
-0.173	-0.013	-0.160
-0.030	-0.031	0.211

Total astigmatism magnitude

0.286	0.035	0.476
0.394	0.074	0.412
0.277	0.072	0.719

Field-averaged astigmatism (interferometry) = 0.31 nm rms
Interferometry precision better than 0.1 nm

Patrick Naulleau



Cross-field astigmatism

Lithographic measurement

0° astigmatism

-0.467	-0.434	-0.188
-0.518	-0.427	-0.036
-0.481	-0.511	-0.002

45° astigmatism

-0.003	-0.237	-0.314
-0.032	-0.079	-0.216
-0.032	-0.089	-0.160

Total astigmatism magnitude

0.468	0.494	0.365
0.519	0.433	0.219
0.482	0.518	0.160

Change since interferometry

0° astigmatism

-0.228	-0.436	-0.504
-0.163	-0.354	-0.415
-0.206	-0.445	-0.690

45° astigmatism

-0.161	-0.202	0.041
0.141	-0.065	-0.056
-0.001	-0.059	-0.371

Total astigmatism magnitude

0.182	0.459	-0.111
0.125	0.359	-0.193
0.205	0.446	-0.559

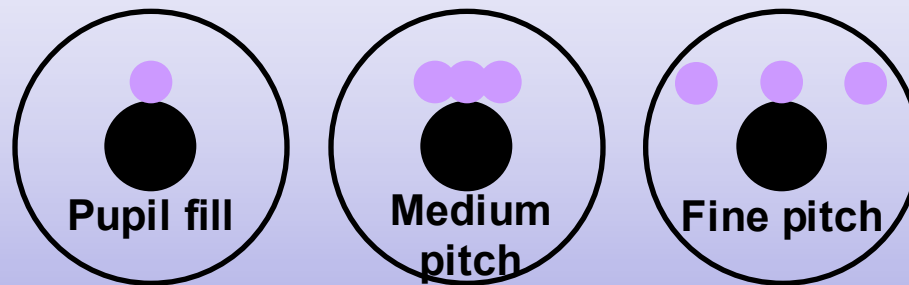
Little change in field-averaged astigmatism
Individual astigmatism terms changed as much as ~0.5 nm

Patrick Naulleau

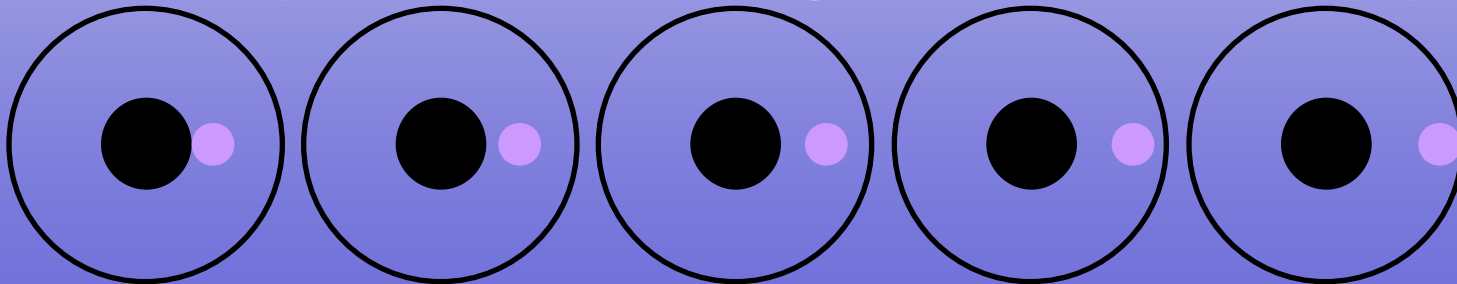


Lithographic quantitative characterization of spherical aberration

- Spherical aberration can be viewed as radially-dependent focus shift
- Programmable illuminator well suited to isolate this error
- Method 1: CD dependent focus shift with y-offset monopole

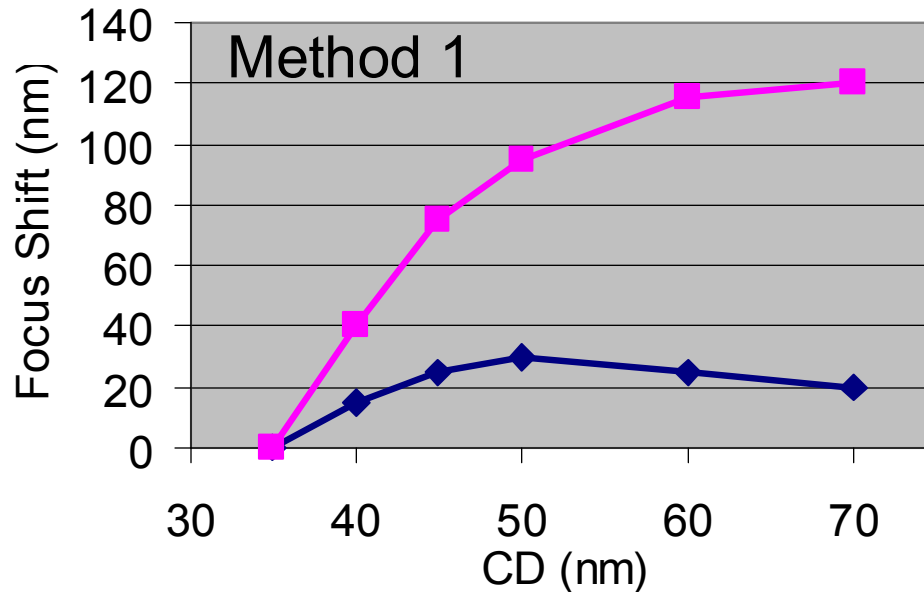


- Method 2: Monopole offset dependent focus shift
 - Shoot multiple small FEMs on single wafer with different pupil fills





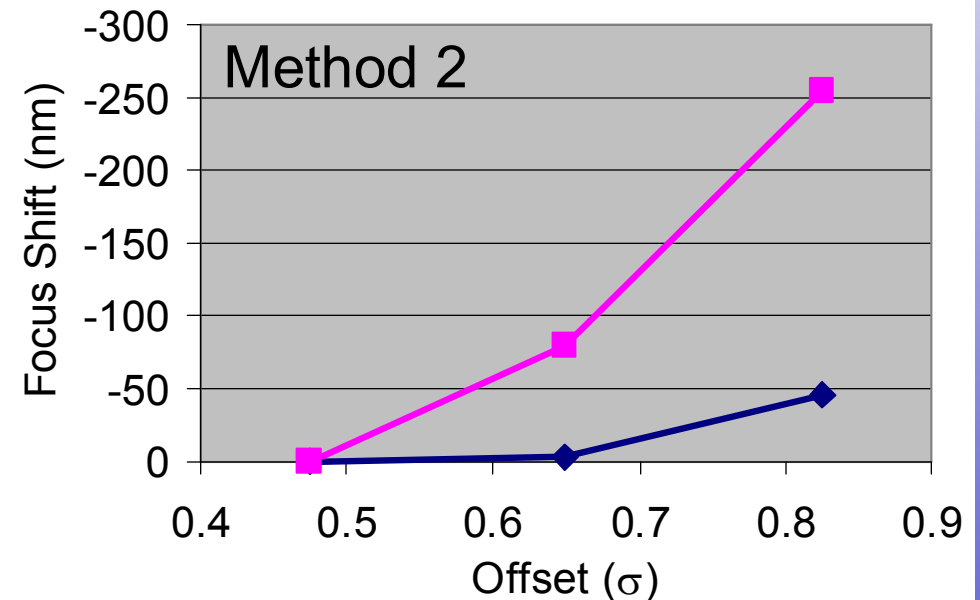
Prolith modeling demonstrates feasibility of measurement of spherical error



— Response of interferometrically measured wavefront

— Response of with spherical aberration set to 0.8 nm rms

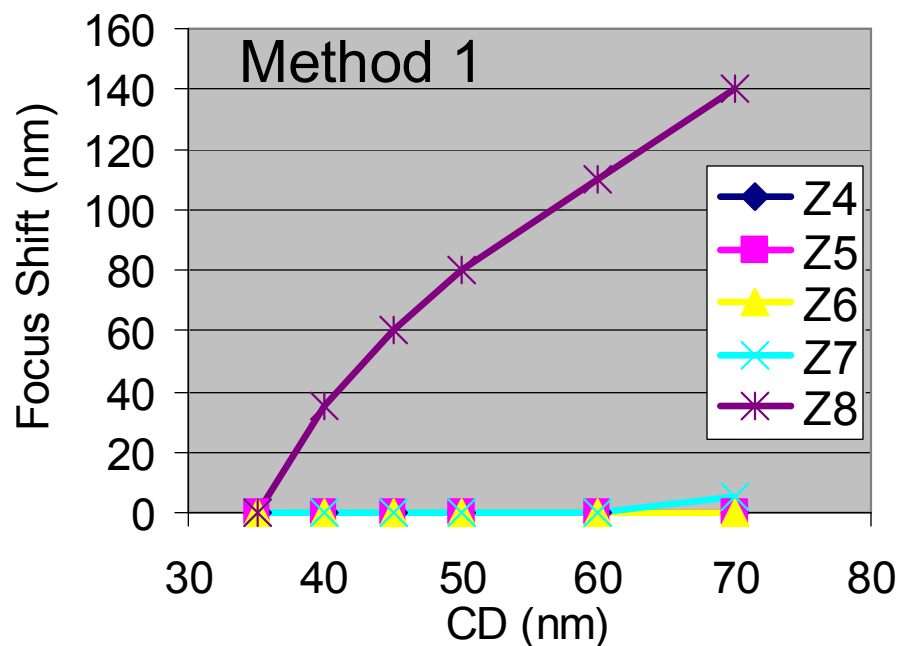
- Both methods provide high sensitivity to spherical error and selectivity from other aberrations in interferometric wavefront



Patrick Naulleau

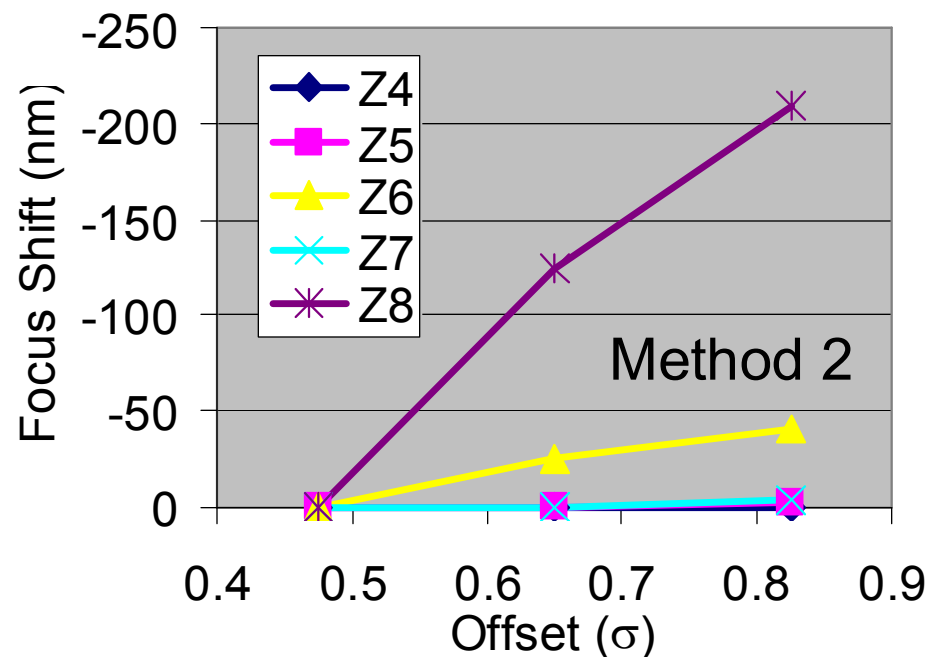


Prolith modeling demonstrates generalized selectivity of measurement



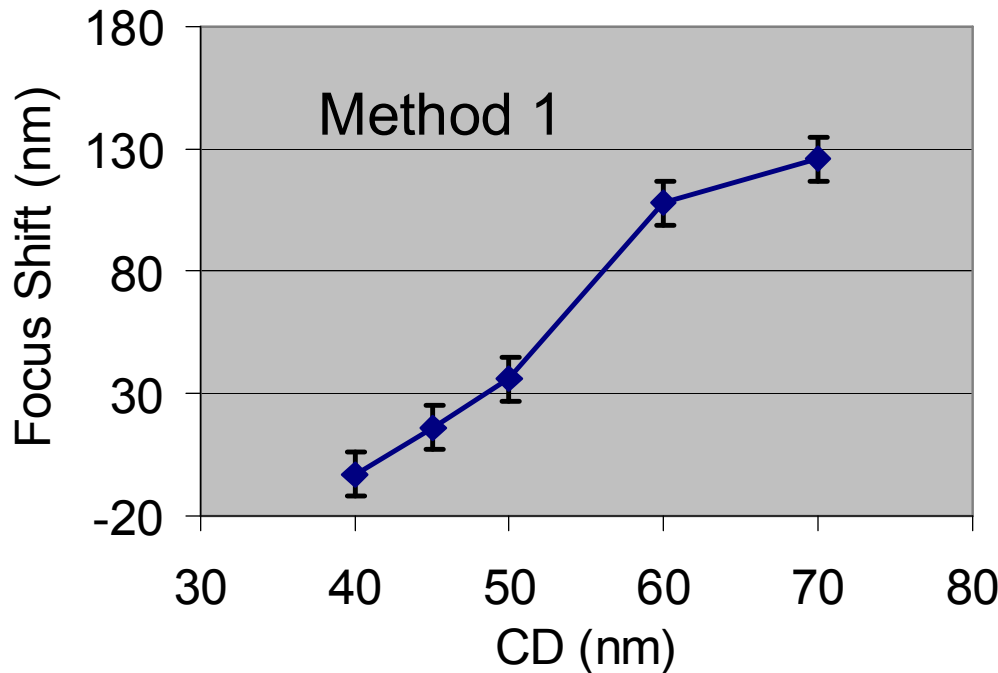
- Good selectivity to spherical error relative to other low order aberrations makes test insensitive to low-order errors in interferometric data

Response to isolated
low-order aberrations of
magnitude 0.8-nm rms

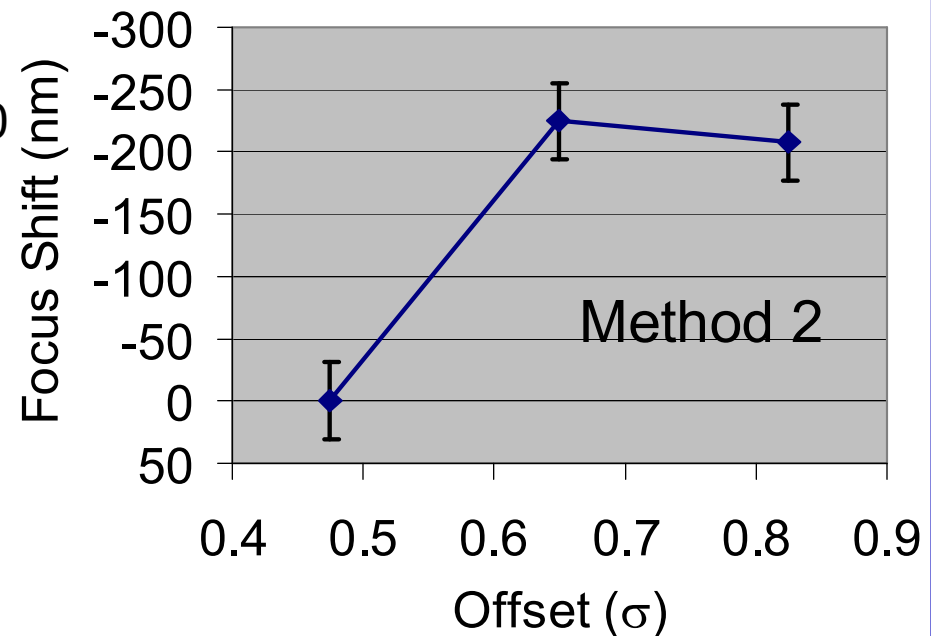




Experimental measurement of spherical error signature in MET optic

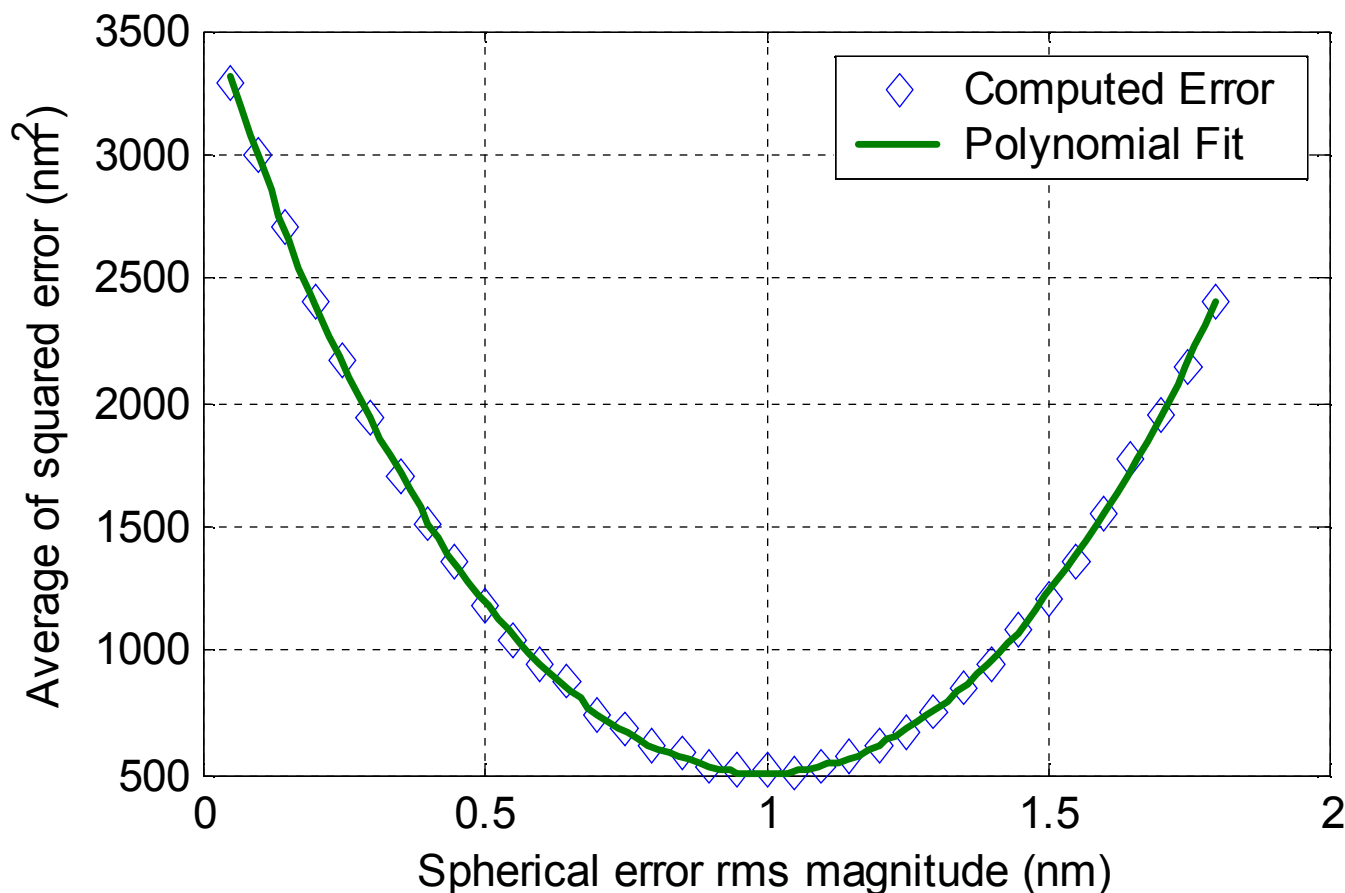


- The presence of spherical error is evident
- Spherical error significantly larger than final alignment state





MET optic determined to have 1-nm rms spherical error

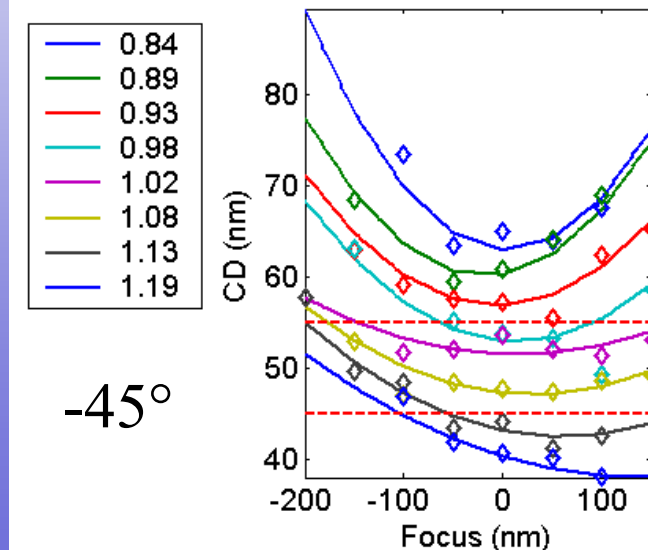
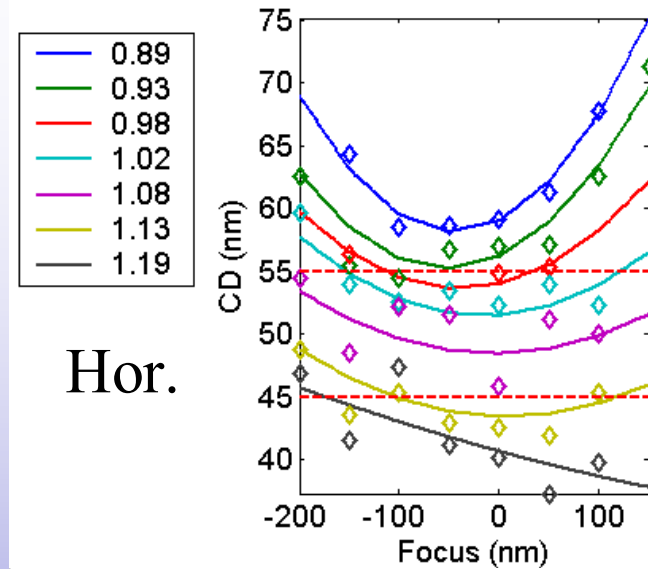
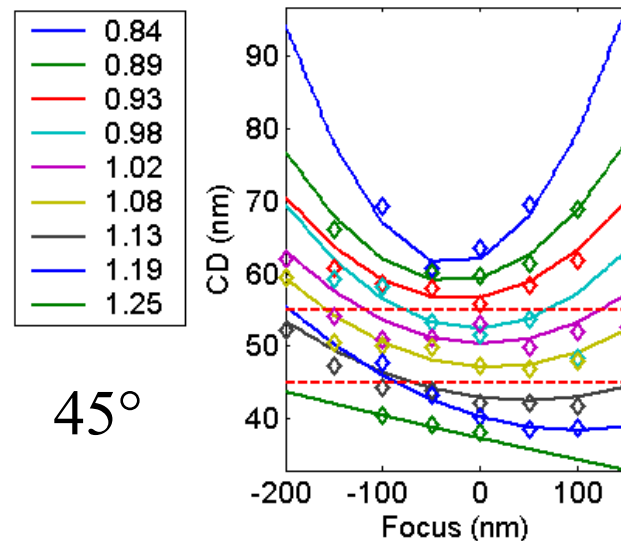
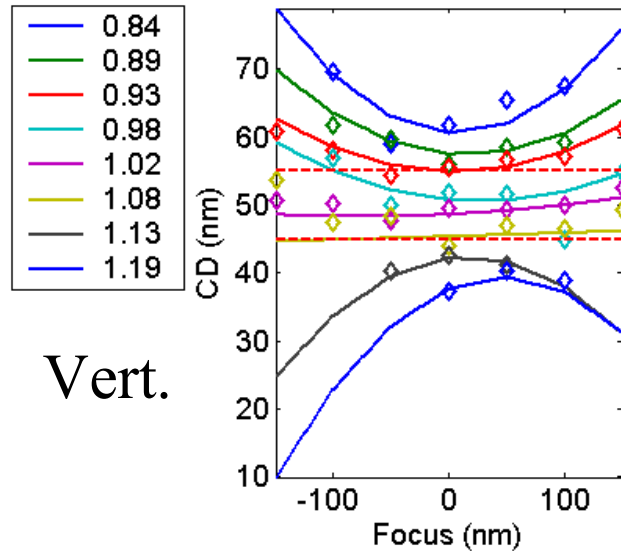


- Least squares data regression to *Prolith* based modeling yields a measurement of 1-nm rms spherical error
- From interferometry, spherical error was expected to be < 0.1-nm rms

Patrick Naulleau



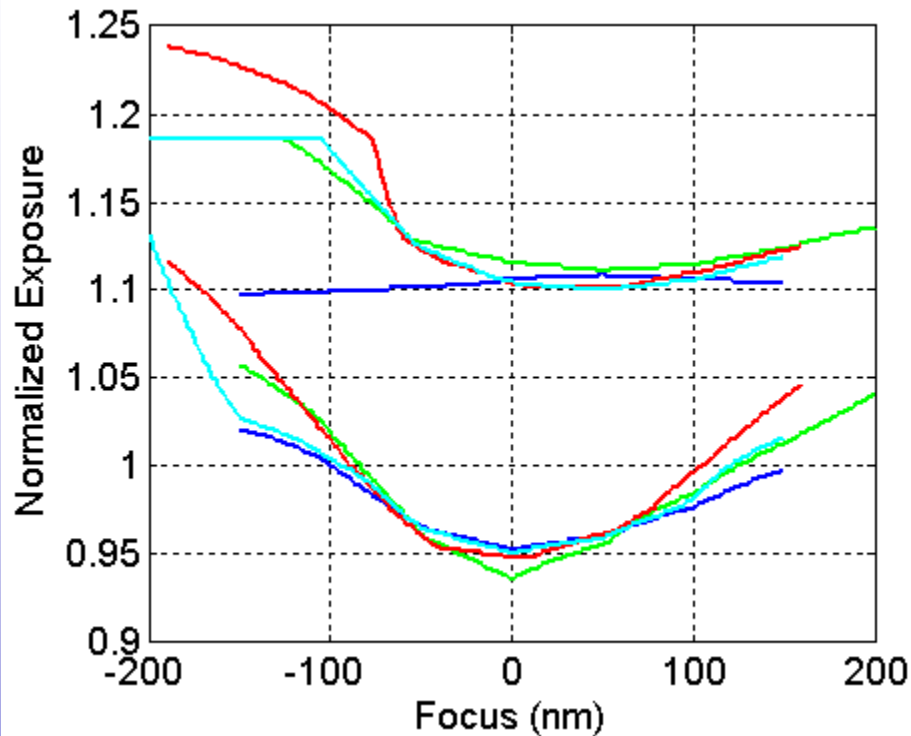
Orientation dependence of performance used for qualitative coma characterization



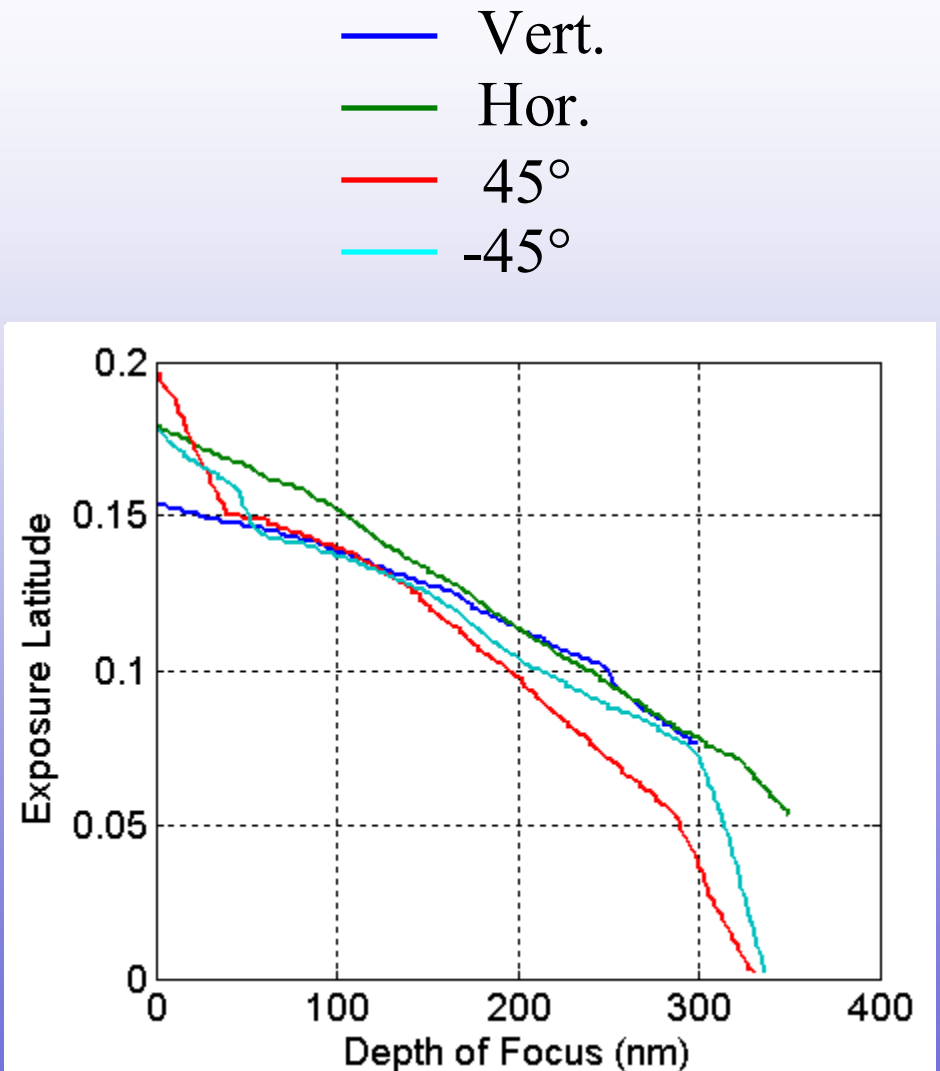
Patrick Naulleau



Orientation dependence of 50-nm performance

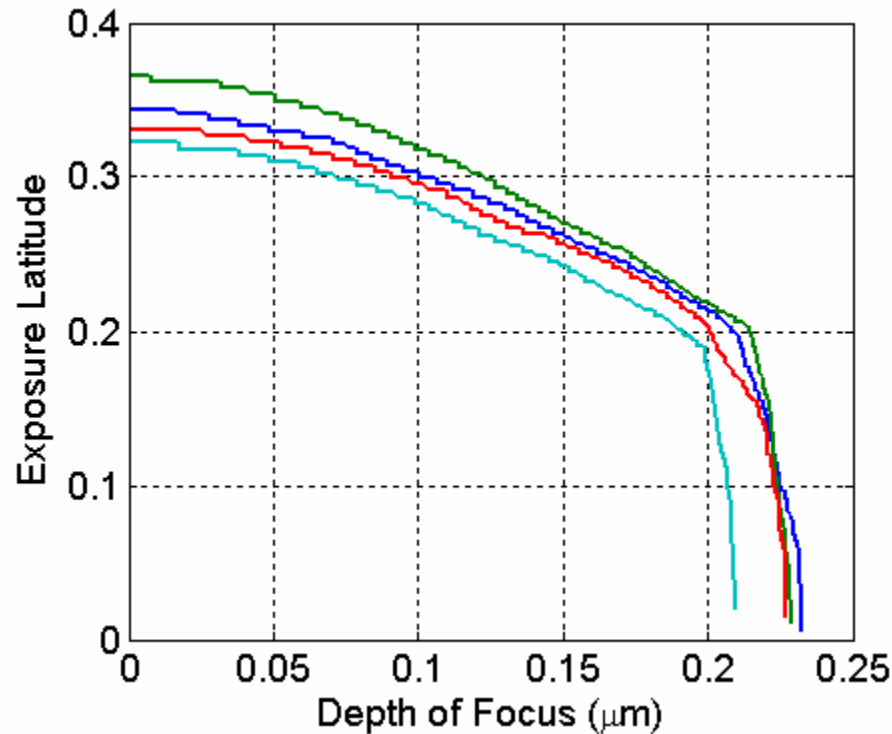


- Possible 50-nm spread in DOF at 10% EL
- Not sure that it statistically relevant

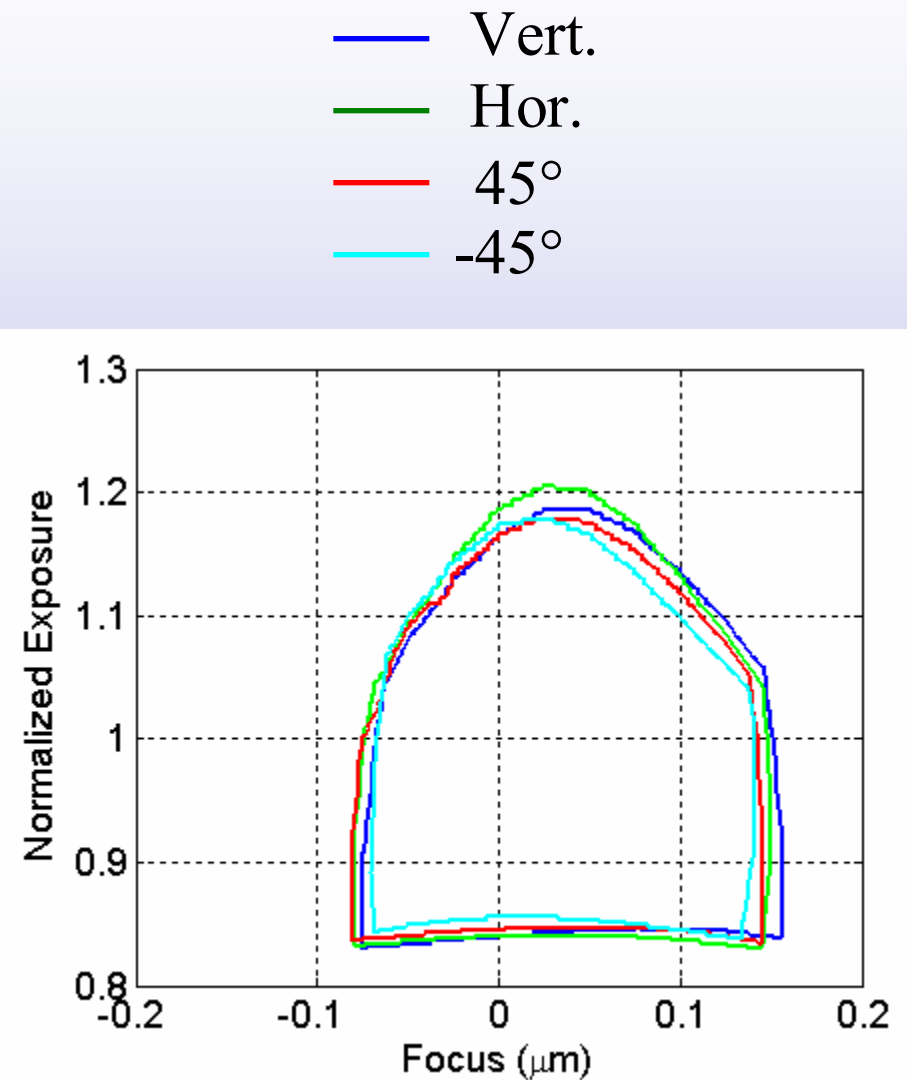




Modeled orientation dependence using lithographically measured wavefront

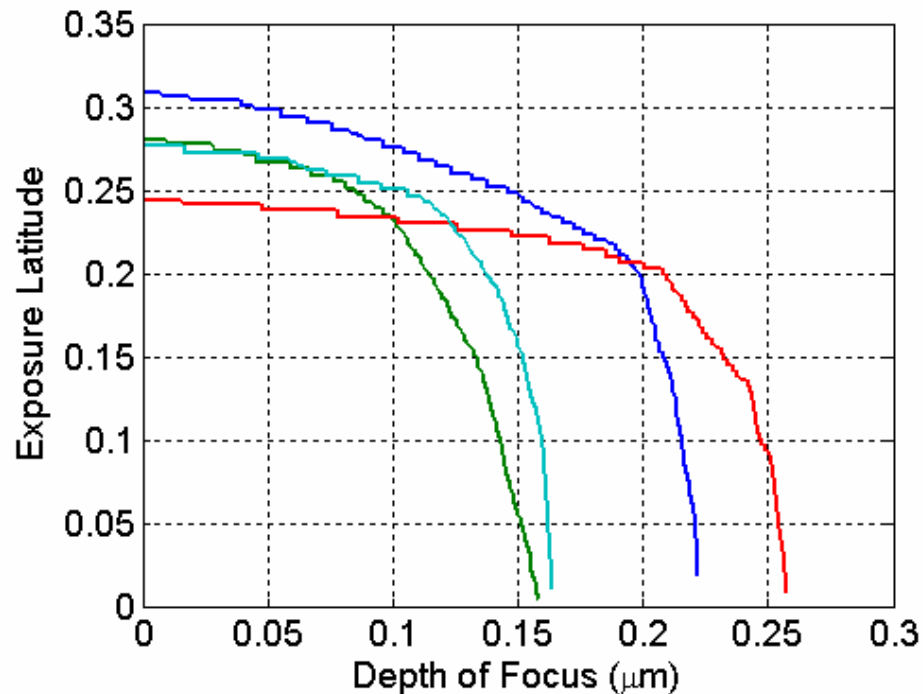


- ~25-nm spread in DOF at 10% EL
- Interferometrically measured coma ~0.5 nm rms

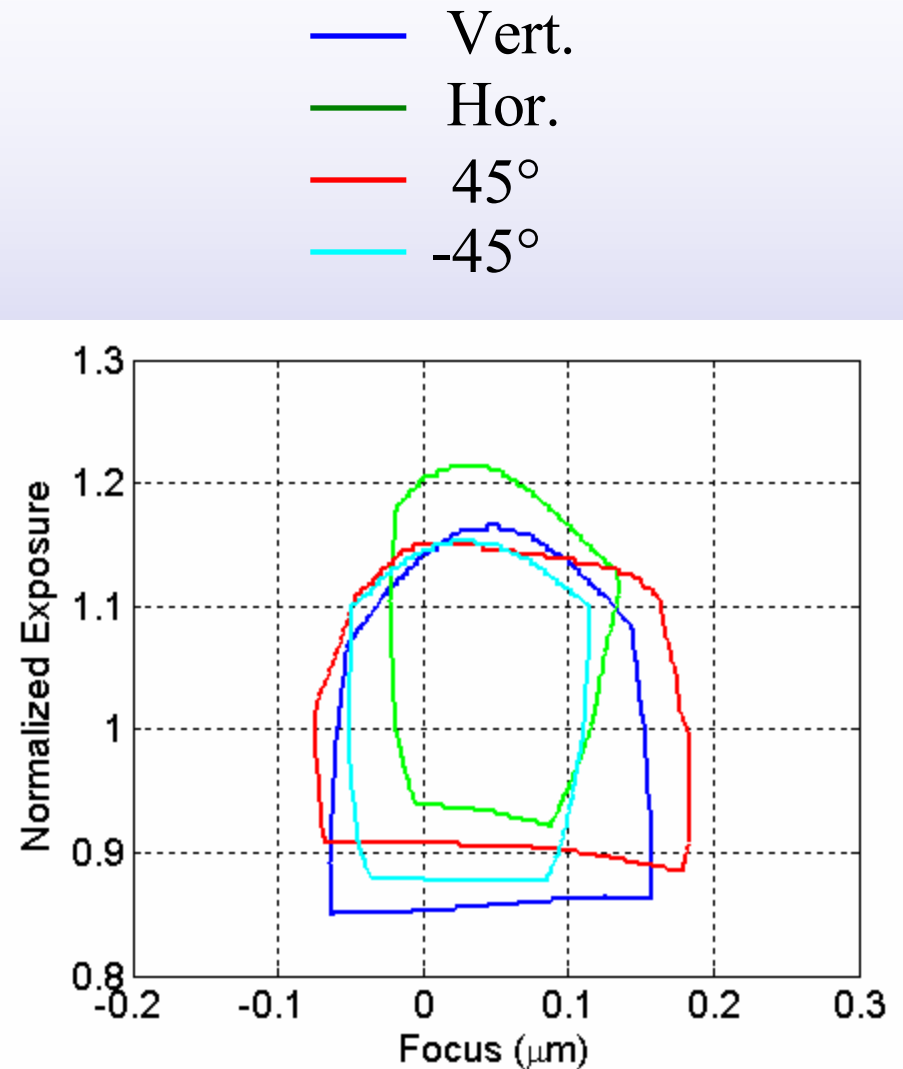




Modeled orientation dependence assuming 1-nm rms coma error

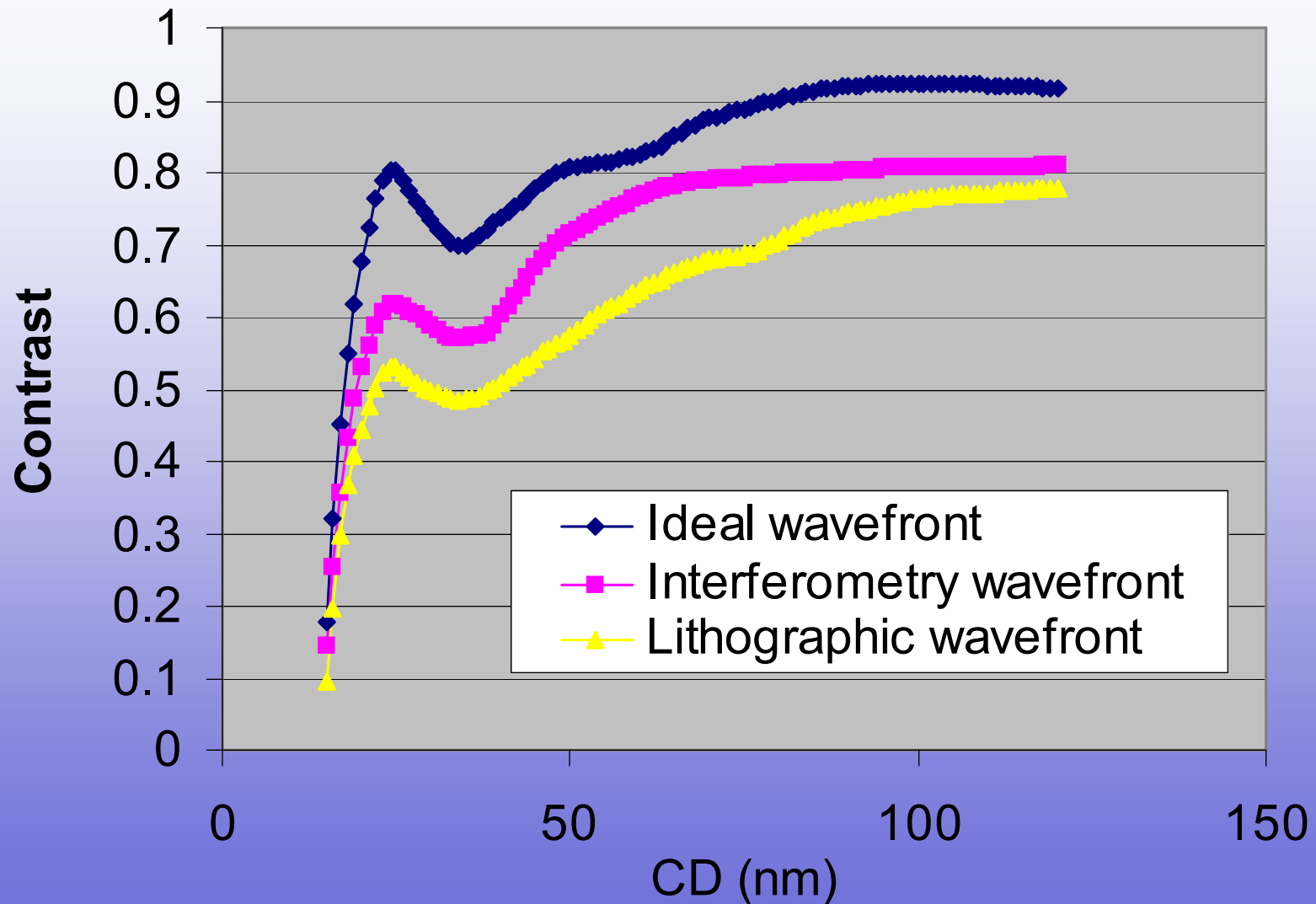


- ~100-nm spread in DOF at 10% EL
- We can safely say that optic has <1 nm coma error





Wavefront difference has significant impact on predicted imaging performance





Summary

- Cross-field astigmatism measurement completed
 - ~0.5-nm rms drift observed since alignment
 - No significant change in field-averaged value
- Spherical aberration measured at center of field
 - 1-nm rms error found
 - ~0.9-nm rms change since alignment
- Qualitative coma measurement reveals no significant change in coma since alignment
 - Final value ~0.5-nm rms
- Results still resist limited



Acknowledgments

Erik Anderson
Paul Denham
Brian Hoef
Keith Jackson
Seno Rekawa
LBNL

Supported by SEMATECH

SEMATECH and the SEMATECH logo are registered servicemarks of SEMATECH, Inc.

